NSN 5961-01-132-8060

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View Online at https://aerobasegroup.com/nsn/5961-01-132-8060 **Inclosure Material:** Plastic **Overall Length:** 0.200 inches **Terminal Length:** 12.5 millimeters **Overall Diameter:** 0.205 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 collector to base voltage/static/emitter open and 30.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 400.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector **Transfer Ratio:** 120.0 static forward current transfer ratio, common-emitter and 240.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: